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Modelling Smart Structures with Segmented Piezoelectric Sensors and Actuators

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ABSTRACT

In this paper, a number of finite element models have been developed for comprehensive modelling of smart structures with segmented piezoelectric sensing and actuating patches. These include an eight-node solid-shell element for modelling homogeneous and laminated host structures as well as an eight-node solid-shell and a four-node piezoelectric membrane elements for modelling surface bonded piezoelectric sensing and actuating patches. To resolve the locking problems in these elements and improve their accuracy, assumed natural strain and hybrid stress formulations are employed. Furthermore, piezoelectric patches are often coated with metallization. The concept of electric nodes is introduced that can eliminate the burden of constraining the equality of the electric potential for physical nodes lying on the same metallization. A number of problems are studied by the developed finite element models and comparisons with others ad hoc element models are presented.


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1. INTRODUCTION

A popular form of smart structure contains a system of piezoelectric sensors which convert the strains of the host structure into electric signals. These signals are fed into microprocessors which in turn activate a system of piezoelectric actuators so that the structure response with respect to external excitations can be altered in real time, see Figure 1. A most widely exploited application of the smart structure technology is active vibration control or active damping. While it is possible to embed the sensors and actuators inside the host structure, segmentary surface-bonded sensors and actuators are far more popular due to their low fabrication cost.

Designing and analyzing practical smart structures inevitably require the use of finite element method. For this purpose, there have been a number ad hoc finite element models developed [1-10]. Owing to the geometric complexity of the surface bonded sensors and actuators which are most conveniently modelled by continuum elements (no rotational d.o.f.), many of the developed finite element models are continuum in nature [1,4,5,7,8]. However, strict considerations of locking deficiencies are often lacking in the course of developing these finite element models. It is unfortunate that solid elements when applied to plate and shell analyses can be plagued by the largest number of finite element deficiencies which include shear, membrane, trapezoidal, thickness and dilatational lockings. Thus, solid-to-plate/shell transition elements may have to be adopted whereas excessive aspect ratios of the solid and transition elements must be avoided. Alternatively, transition elements can be avoided by introducing numerical constraints to tie up the rotations in plate/shell elements with the translations in the solid elements [8]. This practice is tedious and also adversely affect the condition of the system equation.

We shall start with an eight-node element which possesses the same kinetic d.o.f.s as the standard eight-node solid element but is applicable to thin plate/shell analyses without suffering the afore-mentioned lockings. The element is then generalized for modelling piezoelectric materials. Noting that the piezoelectric patch is always coated with metallization which constitutes an equal-potential surface, the concept of electric nodes is introduced that can effectively eliminate the burden of constraining the equality of the electric potential for the nodes lying on the same metallization. A four-node membrane piezoelectric element is also developed that can more efficiently model the piezoelectric patches (e.g. PVDF) which are very thin compared to the host structures. A number of popular examples are considered by the new finite element models to illustrate their accuracy and efficacy in smart structure modelling.
2. GEOMETRIC AND KINEMATIC INTERPOLATION

Figure 2 shows an eight-node hexahedral element in which \( \xi, \eta \) and \( \zeta \) are the natural coordinates. Let \( \zeta \) be aligned with the transverse direction of the shell, the geometric interpolation can be expressed as:

\[
\mathbf{X}(\xi, \eta, \zeta) = \sum_{i=1}^{4} N_i(\xi, \eta) \left( \frac{1+\zeta}{2} \mathbf{X}_i^+ + \frac{1-\zeta}{2} \mathbf{X}_i^- \right) = (a_0 + a_1 \xi + a_2 \eta + a_3 \zeta) + \zeta (b_0 + b_1 \xi + b_2 \eta + b_3 \zeta) = \mathbf{X}_0 + \zeta \mathbf{X}_n
\]

(1)

where

\[
N_i = (1-\xi)(1-\eta)/4, \quad N_2 = (1+\xi)(1-\eta)/4, \quad N_3 = (1+\xi)(1+\eta)/4, \quad N_4 = (1-\xi)(1+\eta)/4
\]

\( \mathbf{X}, \mathbf{X}_j^+ \) and \( \mathbf{X}_j^- \) are the coordinate vectors, its value at the \( j^+ \) and \( j^- \) nodes of the element.

\[
\mathbf{a}_0 = \begin{bmatrix}
1 \\
1/8 \\
-1 \\
-1
\end{bmatrix}
\quad \mathbf{a}_1 = \begin{bmatrix}
+1/2 \\
+1/2 \\
1/8 \\
-1
\end{bmatrix}
\quad \mathbf{a}_2 = \begin{bmatrix}
0 \\
1/2 \\
-1/8 \\
0
\end{bmatrix}
\quad \mathbf{a}_3 = \begin{bmatrix}
0 \\
1/2 \\
-1/8 \\
0
\end{bmatrix}
\quad \mathbf{b}_0 = \begin{bmatrix}
+1/2 \\
1/2 \\
1/8 \\
1/8
\end{bmatrix}
\quad \mathbf{b}_1 = \begin{bmatrix}
+1/2 \\
1/2 \\
1/8 \\
1/8
\end{bmatrix}
\quad \mathbf{b}_2 = \begin{bmatrix}
0 \\
1/2 \\
-1/8 \\
0
\end{bmatrix}
\quad \mathbf{b}_3 = \begin{bmatrix}
0 \\
1/2 \\
-1/8 \\
0
\end{bmatrix}
\]

\( \mathbf{I}_n \) is the \( m \)-th order identity matrix.

Similarly, the displacement interpolation can be expressed as:

\[
\mathbf{U}(\xi, \eta, \zeta) = \sum_{i=1}^{4} N_i(\xi, \eta) \left( \frac{1+\zeta}{2} \mathbf{U}_i^+ + \frac{1-\zeta}{2} \mathbf{U}_i^- \right) = \mathbf{N}(\xi, \eta) \mathbf{q}_o + \zeta \mathbf{N}(\xi, \eta) \mathbf{q}_n = \mathbf{U}_0 + \zeta \mathbf{U}_n
\]

(2)

in which

\[
\mathbf{N}(\xi, \eta) = [N_1 \mathbf{I}_3, N_2 \mathbf{I}_3, N_3 \mathbf{I}_3, N_4 \mathbf{I}_3], \quad \mathbf{q}_o = \frac{1}{2} \begin{bmatrix}
\mathbf{U}_1^+ + \mathbf{U}_1^- \\
\mathbf{U}_2^+ + \mathbf{U}_2^- \\
\mathbf{U}_3^+ + \mathbf{U}_3^- \\
\mathbf{U}_4^+ + \mathbf{U}_4^-
\end{bmatrix}, \quad \mathbf{q}_n = \frac{1}{2} \begin{bmatrix}
\mathbf{U}_1^+ - \mathbf{U}_1^- \\
\mathbf{U}_2^+ - \mathbf{U}_2^- \\
\mathbf{U}_3^+ - \mathbf{U}_3^- \\
\mathbf{U}_4^+ - \mathbf{U}_4^-
\end{bmatrix}
\]

Moreover, \( \mathbf{U}, \mathbf{U}_j^+ \) and \( \mathbf{U}_j^- \) are the displacement vector with respect to the global Cartesian coordinates, its value at the \( j^+ \) and \( j^- \) nodes of the element, respectively.

3. ASSUMED NATURAL SHEAR AND THICKNESS STRAINS

In this section, the strain-displacement relation of the element by incorporating the commonly employed geometric assumptions in shells will be presented. With reference to the interpolations of \( \mathbf{X} \) and \( \mathbf{U} \), the infinitesimal covariant or natural strain components are:

\[
\varepsilon_\zeta = \mathbf{X}_\zeta^T \mathbf{U}_\zeta, \quad \varepsilon_\eta = \mathbf{X}_\eta^T \mathbf{U}_\eta, \quad \gamma_{\xi\eta} = \mathbf{X}_{\xi}^T \mathbf{U}_{\xi} + \mathbf{X}_{\eta}^T \mathbf{U}_{\eta},
\]
\[ \varepsilon_\zeta = X_\zeta^T U_\zeta, \quad \gamma_{\zeta\zeta} = X_{\zeta\zeta}^T U_{\zeta\zeta} + X_{\zeta}^T U_\zeta, \quad \gamma_{\zeta\eta} = X_{\zeta\eta}^T U_\eta + X_{\eta}^T U_\zeta \]  

(3)

Following the practice in most shell element formulations, the first and second order \( \zeta \)-terms are truncated in transverse shear strains (\( \gamma_{\zeta\zeta} \) and \( \gamma_{\zeta\eta} \)) and the tangential strains (\( \varepsilon_\zeta, \varepsilon_\eta \) and \( \gamma_{\zeta\eta} \)), respectively. Thus,

\[ \varepsilon_\zeta = \varepsilon_\zeta^m + \zeta \varepsilon_\zeta^b, \quad \varepsilon_\eta = \varepsilon_\eta^m + \zeta \varepsilon_\eta^b, \quad \varepsilon_\zeta = X_{\zeta\eta}^T N q_\eta, \quad \gamma_{\zeta\eta} = \gamma_{\zeta\eta}^m + \zeta \gamma_{\zeta\eta}^b, \]

\[ \gamma_{\zeta\zeta} = (b_0 + b_1 \xi + b_2 \eta \xi + b_3 \eta)^T N_{\zeta\zeta} q_\eta + (a_1 + a_2 \eta)^T N q_\eta, \]

\[ \gamma_{\zeta\eta} = (b_0 + b_1 \xi + b_2 \eta \xi + b_3 \eta)^T N_{\zeta\eta} q_\eta + (a_3 + a_2 \xi)^T N q_\eta, \]  

(4)

in which the membrane “\( m \)” and bending “\( b \)” strain components can be derived from equation (1) and equation (2) as:

\[ \varepsilon_\zeta^m = (a_1 + a_2 \eta)^T N_{\zeta\zeta} q_\eta, \quad \varepsilon_\eta^m = (b_1 + b_2 \eta)^T N_{\zeta\eta} q_\eta + (a_1 + a_2 \eta)^T N_{\zeta\eta} q_\eta, \]

\[ \varepsilon_\zeta^b = (a_3 + a_2 \xi)^T N_{\zeta\zeta} q_\eta, \quad \varepsilon_\eta^b = (b_3 + \xi b_2)^T N_{\zeta\eta} q_\eta + (a_3 + \xi a_2)^T N q_\eta, \]

\[ \gamma_{\zeta\zeta}^m = [(a_1 + a_2 \eta)^T N_{\zeta\eta} q_\eta + (a_3 + \xi a_2)^T N_{\zeta\eta} q_\eta], \]

\[ \gamma_{\zeta\eta}^b = [(b_1 + b_2 \eta)^T N_{\zeta\eta} q_\eta + (b_3 + \xi b_2)^T N_{\zeta\eta} q_\eta + [(a_1 + a_2 \eta)N_{\zeta\eta} + (a_3 + \xi a_2)^T N_{\zeta\eta} q_\eta, \]

(5)

As the material properties are often defined in a local orthogonal frame \( x-y-z \), it is necessary to obtain the local physical strains from the covariant ones. It will be assumed as usual that the \( z \)-axis and the \( x-y \)-plane are parallel to the \( \zeta \)-axis and mid-surface of the shell, respectively. Hence, the relations between the covariant strains and the local physical strains when approximated by the ones evaluated at the mid-surface are [11] :

\[
\begin{bmatrix}
\varepsilon_x \\
\varepsilon_y \\
\gamma_{xy}
\end{bmatrix} =
\begin{bmatrix}
x_x^2 & x_x y_x & 2x_x x_y \\
y_x y_x & y_x^2 & 2y_x y_y \\
x_x y_y & y_x y_y & x_y^2 + x_x y_x
\end{bmatrix}
\begin{bmatrix}
\varepsilon_x \\
\varepsilon_y \\
\gamma_{xy}
\end{bmatrix},
\begin{bmatrix}
\gamma_{xx} \\
\gamma_{yy} \\
\gamma_{xy}
\end{bmatrix} =
\begin{bmatrix}
x_x & x_y & 1 \\
y_x & y_y & 0 \\
z_x & z_y & 0
\end{bmatrix}
\begin{bmatrix}
\gamma_{xx} \\
\gamma_{yy} \\
\gamma_{xy}
\end{bmatrix},
\varepsilon_z = \frac{1}{z_x^2} \varepsilon_\zeta = \frac{1}{\|X_\zeta\|} \varepsilon_\zeta
\]

(6)

where

\[ x_x = e_x^T X_{0 \zeta}, \quad y_x = e_y^T X_{0 \zeta}, \quad x_y = e_y^T X_{0 \zeta}, \quad y_y = e_y^T X_{0 \zeta}, \quad z_x = e_z^T X_\zeta \]

\[ e_x, e_y, \text{ and } e_z \] are the unit vectors along the local \( x \)-, \( y \)- and \( z \)-directions

Shear locking is due to the excess number of transverse shear strains sampled in the process of integrating the element stiffness matrix. An effective method of resolving shear locking is the assumed natural strain (ANS) method in which the natural transverse shear strains are interpolated from the ones sampled along the element edges. These sampled strains are common to the elements
sharing the same edge. Thus, the number of independent shear strains in the system level can be reduced. Following the standard interpolations of four-node ANS shell elements, the natural transverse shear strains are modified to be [12]:

\[ \tilde{\gamma}_{\xi\xi} = \frac{1 - \eta}{2} \gamma_{\xi\xi}^{\text{ref}} + \frac{1 + \eta}{2} \gamma_{\xi\xi}^{\text{ref}} \quad \text{and} \quad \tilde{\gamma}_{\xi\eta} = \frac{1 - \xi}{2} \gamma_{\xi\eta}^{\text{ref}} + \frac{1 + \xi}{2} \gamma_{\xi\eta}^{\text{ref}} \]

(7)

with which the local Cartesian transverse shear strains \( \tilde{\gamma}_{x\xi} \) and \( \tilde{\gamma}_{y\eta} \) can be obtained by using equation (6).

Another locking phenomenon that plagues solid elements in thin shell analysis is the trapezoidal locking [13]. The strain components leading to the locking is the thickness strain or, equivalently, the normal strain along the thickness direction [14]. ANS can also be adopted to overcome the problem by interpolating the natural thickness strains at the midpoints of the element corners [15], i.e.

\[ \tilde{\varepsilon}_z = N_1 \cdot \varepsilon_z^{\text{ref}} + N_2 \cdot \varepsilon_z^{\text{ref}} + N_3 \cdot \varepsilon_z^{\text{ref}} + N_4 \cdot \varepsilon_z^{\text{ref}} \]

(8)

By consolidating equation (5) to equation (8), the physical strains can be expressed symbolically as:

\[
\begin{bmatrix}
\varepsilon_x \\
\varepsilon_y \\
\gamma_{xy}
\end{bmatrix}
= 
\begin{bmatrix}
\varepsilon_x \\
\varepsilon_y \\
\gamma_{xy}
\end{bmatrix}
+ 
\begin{bmatrix}
\frac{\varepsilon_x + \zeta \varepsilon_y}{\tilde{\gamma}_{xy}}
\end{bmatrix}
\begin{bmatrix}
\varepsilon_x \\
\varepsilon_y \\
\gamma_{xy}
\end{bmatrix}
= 
\begin{bmatrix}
B_x + \zeta B_y \\
B_x + \zeta B_y \\
B_x + \zeta B_y
\end{bmatrix}
q^e , \quad \gamma = \begin{bmatrix}
\tilde{\gamma}_{x\xi} \\
\tilde{\gamma}_{y\eta}
\end{bmatrix} = B, q^e
\]

(9)

where \( B \)’s are independent of \( \zeta \) and \( q^e \) is the element displacement vector. Assuming that transverse shear response is uncoupled from the others, the constitutive relation can be expressed as:

\[
\begin{bmatrix}
\sigma_x \\
\sigma_y \\
\tau_{xy}
\end{bmatrix}
= 
\begin{bmatrix}
C_{x|x} & C_{x|y} & C_{x|z} \\
C_{y|x} & C_{y|y} & C_{y|z} \\
C_{z|x} & C_{z|y} & C_{z|z}
\end{bmatrix}
\begin{bmatrix}
\varepsilon_x \\
\varepsilon_y \\
\gamma_{xy}
\end{bmatrix}
, \quad \tau = \begin{bmatrix}
\tilde{\gamma}_{x\xi} \\
\tilde{\gamma}_{y\eta}
\end{bmatrix} = C, \gamma
\]

(10)

By adopting the usual approximation of the Jacobian determinant

\[ J \approx J_o = J_{\xi=\eta=0} ; \]

(11)

the ANS element which is free from shear and trapezoidal locking can be formulated via the following elementwise potential energy functional:

\[
\Pi_p^e = \frac{1}{2} \int_{\xi_0}^1 \left( \begin{bmatrix}
\varepsilon_x \\
\varepsilon_y \\
\gamma_{xy}
\end{bmatrix}
\right)^T \begin{bmatrix}
C_{x|x} & C_{x|y} & C_{x|z} \\
C_{y|x} & C_{y|y} & C_{y|z} \\
C_{z|x} & C_{z|y} & C_{z|z}
\end{bmatrix}
\begin{bmatrix}
\varepsilon_x \\
\varepsilon_y \\
\gamma_{xy}
\end{bmatrix}
+ \gamma^T C, \gamma - b^T U \right) \mathrm{dv} - \int_{\xi_0}^1 \left( t^T U \right) \mathrm{ds}
\]
\[
\begin{align*}
= \frac{1}{2} \int_{-1}^{+1} \int_{-1}^{+1} \begin{pmatrix} \varepsilon_m \\ \varepsilon_h \end{pmatrix}^T C_G \begin{pmatrix} \varepsilon_m \\ \varepsilon_h \end{pmatrix} + \gamma^T C_T \gamma)2J_{\varepsilon} d\xi d\eta - P^e = \frac{1}{2} (q^e)^T k_{ANS}^e q^e - (f_b^e + f_t^e)^T q^e
\end{align*}
\]

where

\[
C_G = \frac{1}{2} \int_{-1}^{+1} \begin{bmatrix} C_u & \zeta C_u \\ \zeta C_u^T & \zeta^2 C_u \end{bmatrix} d\zeta \text{ is the generalized laminate stiffness matrix}
\]

\[
C_T = \frac{1}{2} \int_{-1}^{+1} C_q d\zeta, \quad V^e \text{ denotes the element domain, } P^e \text{ is the load potential}
\]

\[
k_{ANS}^e = \int_{-1}^{+1} \int_{-1}^{+1} \begin{pmatrix} B_m \\ B_h \end{pmatrix}^T C_G \begin{pmatrix} B_m \\ B_h \end{pmatrix} + B_t^T C_T B_t)2J_{\varepsilon} d\xi d\eta
\]

\[
f_b^e = \int_{V^e} N^T b dv \text{ is the elementwise mechanical force due to the body force } b
\]

\[
f_t^e = \int_{S_{\sigma}} N^T t ds \text{ is the elementwise mechanical force due to the surface traction } t
\]

\[
S_{\sigma}^e \text{ is the portion of the element boundary being prescribed with surface traction}
\]

Moreover, \( C_G \) and \( C_T \) relate the following generalized stresses to the strains \( \varepsilon_m, \varepsilon_{||}, \varepsilon_h \) and \( \gamma \) as :

\[
\begin{align*}
\begin{bmatrix} N \\ M \end{bmatrix} = \frac{1}{2} \int_{-1}^{+1} \begin{bmatrix} \sigma_m \\ \sigma_{||} \\ \zeta \sigma_{\perp} \end{bmatrix} d\zeta = C_G \begin{pmatrix} \varepsilon_m \\ \varepsilon_{||} \\ \varepsilon_h \end{pmatrix}, \quad T = \frac{1}{2} \int_{-1}^{+1} \tau d\zeta = C_T \gamma
\end{align*}
\]

Though the above ANS element is free from shear and trapezoidal locking, it is plagued by thickness locking. In other words, plane strain condition instead of the expected plane stress condition will be predicted when the element is loaded by bending moment. The locking phenomenon can be overcome by modifying the generalized laminate stiffness \( C_G \) to \( \tilde{C}_G \) as given in Appendix.

4. SOLID-SHELL ELEMENT FOR LAMINATED MATERIALS

To apply hybrid stress (HS) formulation to the above ANS solid-shell element as a means to
improve the latter’s in-plane response, the following elementwise modified Hellinger-Reissner functional can be invoked:

\[
\Pi_{HR}^e = \int \left( -\frac{1}{2} \begin{bmatrix} N \end{bmatrix}^T \tilde{C}_G^{-1} \begin{bmatrix} N \end{bmatrix} + \begin{bmatrix} N \end{bmatrix}^T \begin{bmatrix} \varepsilon_m \end{bmatrix} \right) \frac{1}{2} T' C_T^{-1} T + T' \gamma - b' \mathbf{U})dv - \int T' \mathbf{U}ds
\] (14)

The following orthogonal constant and non-constant stress modes are chosen in a way similar to that of Pian’s eight-node element [16,17]:

\[
\begin{bmatrix} N \\ M \end{bmatrix} = \begin{bmatrix} I_4 & 0_{4\times 3} \\ 0_{3 \times 4} & I_3 \end{bmatrix}, \quad T = \begin{bmatrix} \mathbf{P}_{NH} & 0_{4 \times 2} \\ 0_{3 \times 5} & \mathbf{P}_{MH} \end{bmatrix}, \quad \mathbf{P}_{NH}, \mathbf{P}_{MH}, \mathbf{P}_{TH}
\] (15)

where

\[
\mathbf{P}_{NI} = \frac{1}{J_o} \begin{bmatrix} \xi x_n x_{\eta n} & 0 & \eta x_n x_{\eta n} & 0 & 0 & \xi x_n x_{\eta n} & 0 & \eta x_n x_{\eta n} & 0 & 0 \end{bmatrix}, \quad \mathbf{P}_{MH} = \frac{1}{J_o} \begin{bmatrix} \xi x_n x_{\eta n} & \eta x_n x_{\eta n} & \xi x_n x_{\eta n} & \eta x_n x_{\eta n} & \xi x_n x_{\eta n} & \eta x_n x_{\eta n} \end{bmatrix}, \quad \mathbf{P}_{TH} = \frac{1}{J_o} \begin{bmatrix} \xi x_n x_{\eta n} & \eta x_n x_{\eta n} & \xi x_n x_{\eta n} & \eta x_n x_{\eta n} \end{bmatrix}
\]

\[
J_o = J_{\xi = \eta = \zeta = 0}; \quad \xi = x_{\xi = \eta = \zeta = 0}; \quad \eta = y_{\xi = \eta = \zeta = 0}; \quad \xi = x_{\xi = \eta = \zeta = 0}; \quad \eta = y_{\xi = \eta = \zeta = 0}
\]

\[
\mathbf{0}_{m \times n} \text{ is the } m \times n \text{ zero matrix, } \beta \text{'s are the vectors of stress coefficients}
\]

Adopting the usual approximation in equation (11), the functional can be simplified to:

\[
\Pi_{HR}^e = \frac{1}{2} \left( \begin{bmatrix} \mathbf{\beta}_{NC} \\ \mathbf{\beta}_{MC} \end{bmatrix}^T \tilde{C}_G^{-1} \begin{bmatrix} \mathbf{\beta}_{NC} \\ \mathbf{\beta}_{MC} \end{bmatrix} + \begin{bmatrix} \mathbf{\beta}_{NH} \\ \mathbf{\beta}_{MH} \end{bmatrix}^T \mathbf{H}_G \begin{bmatrix} \mathbf{\beta}_{NH} \\ \mathbf{\beta}_{MH} \end{bmatrix} + \mathbf{\beta}_{TC}^T C_T^{-1} \mathbf{\beta}_{TC} + \mathbf{\beta}_{TH}^T C_T^{-1} \mathbf{\beta}_{TH} \right) + \left( \begin{bmatrix} \mathbf{\beta}_{NC} \\ \mathbf{\beta}_{MC} \end{bmatrix}^T \mathbf{G}_{NC} + \begin{bmatrix} \mathbf{\beta}_{NH} \\ \mathbf{\beta}_{MH} \end{bmatrix}^T \mathbf{G}_{NH} \right) \begin{bmatrix} \mathbf{q}^e - (\mathbf{f}^e + \mathbf{f}^f) \end{bmatrix}^T
\] (16)

where

\[
\mathbf{G}_{NC} = 2 \int_{-1}^{1} \int_{-1}^{1} \mathbf{B}_m J_o d\xi d\eta, \quad \mathbf{G}_{MC} = 2 \int_{-1}^{1} \int_{-1}^{1} \mathbf{B}_m J_o d\xi d\eta, \quad \mathbf{G}_{NH} = 2 \int_{-1}^{1} \int_{-1}^{1} \mathbf{P}_{NI} \mathbf{B}_m J_o d\xi d\eta
\]

By invoking the stationary nature of \( \Pi_{HR}^e \) with respect to \( \beta \)'s, the functional becomes:
\[ \Pi_{HR}^{e} = \frac{1}{2} (q^e)^T \kappa_{lam}^e q^e - (f_k^e + f_n^e)^T q^e \] (17)

in which the element stiffness matrix for the HS-ANS element is:

\[ \kappa_{lam}^e = \frac{1}{v} \begin{bmatrix} \mathbf{G}_{NC} \beta \mathbf{S}_{NC} \mathbf{G}_{NC} \pi \mathbf{H}^{-1} \mathbf{G}_{NH}^T \mathbf{G}_{NH} \pi \mathbf{G}_{MC}^T \mathbf{C}_{TC} \mathbf{G}_{TC} + \mathbf{G}_{TH}^T \mathbf{H}^{-1} \mathbf{G}_{TH} \end{bmatrix} \]

5. SOLID-SHELL ELEMENT FOR HOMOGENEOUS MATERIALS

If the material is homogeneous instead of laminated, the conventional elementwise Hellinger-Reissner can be employed:

\[ \Pi_{HR}^{e} = \int_{\mathcal{V}} \left( -\frac{1}{2} \mathbf{\sigma}_n \right)^T \mathbf{S}_n \left( \mathbf{\sigma}_n \right) - \frac{1}{2} \mathbf{\tau}^T \mathbf{S}_{1} \mathbf{\tau} + \left( \mathbf{\sigma}_n \right)^T \mathbf{\tau} - \mathbf{b}^T \mathbf{U} \right) d\mathcal{V} - \int_{\mathcal{S}_n} \mathbf{t}^T \mathbf{U} d\mathcal{S} \] (18)

where

\[ \mathbf{S}_n = \begin{bmatrix} \mathbf{S} & \mathbf{S} & \mathbf{S} \\ \mathbf{S}^T & \mathbf{S}^T & \mathbf{S}^T \end{bmatrix} = \begin{bmatrix} \mathbf{C} & \mathbf{C} & \mathbf{C} \\ \mathbf{C}^T & \mathbf{C}^T & \mathbf{C}^T \end{bmatrix}^{-1} = \mathbf{C}^{-1} \]

In analogous to the laminated element, the assumed stress field is taken to be:

\[ \begin{bmatrix} \mathbf{\sigma}_n \\ \mathbf{\sigma}_n \\ \mathbf{\sigma}_n \end{bmatrix} = \begin{bmatrix} \mathbf{I}_{1} & \mathbf{P}_{NH} & \mathbf{P}_{NH} \\ \mathbf{0}_{1x3} & \mathbf{0}_{1x2} & \mathbf{0}_{1x2} \end{bmatrix} \begin{bmatrix} \mathbf{\beta}_{NC} \\ \mathbf{\beta}_{NH} \\ \mathbf{\beta}_{MC} \end{bmatrix}, \quad \mathbf{\tau} = \begin{bmatrix} \mathbf{I}_{2} & \mathbf{P}_{TH} & \mathbf{P}_{TH} \end{bmatrix} \begin{bmatrix} \mathbf{\beta}_{TC} \\ \mathbf{\beta}_{TH} \end{bmatrix} \] (19)

By substituting equations (9) and (19) into the functional, the latter becomes:

\[ \Pi_{HR}^{e} = -\frac{1}{2} (\mathbf{\beta}_{NC}^T \mathbf{S}_{NC} \mathbf{\beta}_{NC} + \mathbf{\beta}_{NH}^T \mathbf{H}_{NH} \mathbf{\beta}_{NH} + \frac{3}{2} \mathbf{\beta}_{MC}^T \mathbf{S}_{MC} \mathbf{\beta}_{MC} + \frac{1}{3} \mathbf{\beta}_{TH}^T \mathbf{H}_{TH} \mathbf{\beta}_{TH} + \mathbf{\beta}_{TC}^T \mathbf{S}_{TC} \mathbf{\beta}_{TC} + \mathbf{\beta}_{TH}^T \mathbf{H}_{TH} \mathbf{\beta}_{TH}) \]

\[ + (\mathbf{\beta}_{NC}^T \mathbf{G}_{NC} + \mathbf{\beta}_{NH}^T \mathbf{G}_{NH} + \frac{1}{3} \mathbf{\beta}_{MC}^T \mathbf{G}_{MC} + \frac{1}{3} \mathbf{\beta}_{TH}^T \mathbf{G}_{TH} + \mathbf{\beta}_{TC}^T \mathbf{G}_{TC} + \mathbf{\beta}_{TH}^T \mathbf{G}_{TH}) q^e - (f_k^e + f_n^e)^T q^e \] (20)

By invoking the stationary nature of \( \Pi_{HR}^{e} \) with respect to \( \mathbf{\beta} \)'s, the following HS-ANS element stiffness matrix is obtained:

\[ \kappa_{hom}^e = \frac{1}{v} \begin{bmatrix} \mathbf{G}_{NC}^T \mathbf{S}_{NC} \mathbf{G}_{NC} + \frac{1}{3} \mathbf{G}_{MC}^T \mathbf{S}_{MC}^{-1} \mathbf{G}_{MC} + \frac{1}{v} \mathbf{G}_{TC}^T \mathbf{C}_{TC} \mathbf{G}_{TC} \\ \mathbf{G}_{NH}^T \mathbf{H}_{NH}^{-1} \mathbf{G}_{NH} \end{bmatrix} + \frac{1}{3} \mathbf{G}_{MC}^T \mathbf{H}_{MC}^{-1} \mathbf{G}_{MC} + \mathbf{G}_{TH}^T \mathbf{H}_{TH}^{-1} \mathbf{G}_{TH} \] (21)
where the undefined matrices are:

\[
\mathbf{H}_{NH} = 2 \int_{-1}^{1} \mathbf{P}^T_{NH} \mathbf{S}_{NH} \mathbf{P}_{NH} J_0 d\xi d\eta, \quad \mathbf{H}_{MH} = 2 \int_{-1}^{1} \mathbf{P}^T_{MH} \mathbf{S}_{MH} \mathbf{P}_{MH} J_0 d\xi d\eta, \quad \mathbf{H}_{TH} = 2 \int_{-1}^{1} \mathbf{P}^T_{TH} \mathbf{S}_{TH} \mathbf{P}_{TH} J_0 d\xi d\eta
\]

As a matter fact, the element stiffness can also be degenerated from equation (17) by noting that

\[
\tilde{\mathbf{C}}_G = \begin{bmatrix}
\mathbf{C}_u & \mathbf{C}_v & \mathbf{0}_{3 \times 3} \\
\mathbf{C}_v^T & \mathbf{C}_u^T & \mathbf{0}_{3 \times 3} \\
\mathbf{0}_{3 \times 3} & \mathbf{0}_{3 \times 1} & S^{-1}_{\varepsilon}/3
\end{bmatrix}
\]

for homogeneous materials (see Appendix).

### 6. SOLID-SHELL ELEMENT FOR PIEZOELECTRIC PATCHES

Piezoelectric patches used for surfaced-bonded segmentary sensors and actuators are always coated with metallization such as printed silver ink. Compared to the overall thickness of the patches, the metallization thickness can be ignored. Hence, the metallization is not separately modelling in the piezoelectric element models. The presence of metallization induces two equal-potential surfaces coincident with the top and bottom surface of the patches. In this section, the afore derived hybrid- HS-ANS solid-shell element will be generalized for modelling the piezoelectric patches and taking into account of the equipotential surfaces.

For generic piezoelectric solid elements, each node are equipped with three translations and electric potential as the nodal d.o.f.s. It would be necessary to constraint the equality of the electric d.o.f.s of the nodes on the same metallization. To avoid this tedious task, the electric d.o.f.s are separated from the kinetic nodes with which kinetic d.o.f.s are associated. The electric node has two d.o.f.s which are the two electric potentials \( \phi_{\text{TOP}} \) and \( \phi_{\text{BOT}} \) on the upper and lower metallizations. Unlike kinetic nodes, electric nodes have no coordinates. For instance, Fig.3 shows two elements that model the same piezoelectric patch and they only need two electric d.o.f.s which are grouped under the electric node “p”. Under the present ways of arranging the nodal d.o.f.s, their connectivities are \([a,c,h,b,d,k,i,p]\) and \([c,f,m,j,d,g,n,k,p]\). The first eight nodes are kinetic nodes and last nodes are electric nodes. The interpolated electric potential is:

\[
\phi = \frac{1}{2} \begin{Bmatrix}
1 + \zeta \\
1 - \zeta
\end{Bmatrix} \frac{\phi_{\text{TOP}}}{\phi_{\text{BOTTOM}}} = \frac{1}{2} \begin{Bmatrix}
1 + \zeta \\
1 - \zeta
\end{Bmatrix} \Phi
\]

With respect to the local Cartesian coordinates defined in Section 3, the electric field can be approximated as:
With two of the electric field components vanished and the poling direction always aligned with the transverse direction, the piezoelectric constitutive relation can be expressed as:

\[
\begin{bmatrix}
\sigma_x \\
\sigma_y \\
\tau \\
\sigma_z \\
D_z
\end{bmatrix} = \begin{bmatrix}
C_{11} & 0_{4x2} & -e_{1} \\
0_{2x4} & C_{12} & 0_{2x1} \\
e_{1} & 0_{1x2} & \varepsilon_{11}
\end{bmatrix} \begin{bmatrix}
e_x \\
\varepsilon_{11} \\
\gamma
\end{bmatrix}
\]

in which \(e_{11} = \{e_{31}, e_{32}, e_{36}, e_{33}\}\) contains the piezo-strain coefficients, \(D_{z}\) and \(\varepsilon_{11} = \varepsilon_{33}\) are respectively the electric displacement and the permittivity coefficient in the transverse direction. By changing the object of the equation,

\[
\begin{bmatrix}
e_x \\
\varepsilon_{11} \\
\gamma
\end{bmatrix} = \begin{bmatrix}
\frac{1}{S} & 0_{4x2} & \frac{1}{E_{1}} \\
0_{2x4} & \frac{1}{S} & 0_{2x1} \\
e_{1} & 0_{1x2} & \frac{1}{E_{1}}
\end{bmatrix} \begin{bmatrix}
\sigma_x \\
\sigma_y \\
\tau \\
\sigma_z \\
D_z
\end{bmatrix} = \begin{bmatrix}
S_{11} & 0_{4x2} & d_{1} \\
0_{2x4} & S_{12} & 0_{2x1} \\
e_{1} & 0_{1x2} & \zeta_{11}
\end{bmatrix} \begin{bmatrix}
\sigma_x \\
\sigma_y \\
\tau \\
\sigma_z \\
D_z
\end{bmatrix}
\]

where \(\zeta_{11} = \zeta_{33}\) is the dielectric coefficient in the transverse direction. To formulate a solid-shell element for piezoelectric patch, the following elementwise hybrid functional is invoked [18,19]:

\[
\Pi^{e} = \int \left( -\frac{1}{2} \begin{bmatrix}
\sigma_x \\
\sigma_y \\
\tau \\
\sigma_z \\
\varepsilon_x
\end{bmatrix}^{T} \begin{bmatrix}
S_{11} & 0_{4x2} & -d_{1} \\
0_{2x4} & S_{12} & 0_{2x1} \\
e_{1} & 0_{1x2} & \zeta_{11}
\end{bmatrix} \begin{bmatrix}
\sigma_x \\
\sigma_y \\
\tau \\
\sigma_z \\
\varepsilon_x
\end{bmatrix} + \begin{bmatrix}
\sigma_x \\
\sigma_y \\
\tau \\
\sigma_z \\
\varepsilon_x
\end{bmatrix}^{T} \begin{bmatrix}
\varepsilon_x \\
\gamma
\end{bmatrix} - b^{T} U \right) dv - \int \left( t^{T} U ds + \int Q_{ds} \right)
\]

where \(S_{Q}^{e}\) is the portion of the element boundary being prescribed with the charge density \(Q\). By invoking equations (9), (11), (19) and (24), we have

\[
\Pi^{e} = -\frac{\nu}{2} \beta^{T} \mathbf{NBC} \mathbf{S}_{NBC} \beta^{T} \mathbf{NBC} - \frac{1}{2} \beta^{T} \mathbf{MNH} \mathbf{MNH} \beta^{T} \mathbf{MNH} - \frac{1}{2} \beta^{T} \mathbf{RHC} \mathbf{RHC} \beta^{T} \mathbf{RHC} - \frac{1}{2} \beta^{T} \mathbf{THH} \mathbf{THH} \beta^{T} \mathbf{THH} - \frac{\nu}{6} \beta^{T} \mathbf{MC} \mathbf{MC} \beta^{T} \mathbf{MC} - \frac{1}{6} \beta^{T} \mathbf{MHI} \mathbf{MHI} \beta^{T} \mathbf{MHI}
\]

\[+ \frac{1}{3} \beta^{T} \mathbf{MC} \mathbf{MC} \mathbf{MC} \mathbf{q}^{e} + \frac{1}{3} \beta^{T} \mathbf{MHI} \mathbf{MHI} \mathbf{q}^{e} + \beta^{T} \mathbf{RHC} \mathbf{RHC} \mathbf{q}^{e} + \beta^{T} \mathbf{THH} \mathbf{THH} \mathbf{q}^{e} - \frac{1}{2} (\Phi^{e})^{T} \mathbf{A} \Phi^{e}
\]

\[+ \beta^{T} \mathbf{MC} \mathbf{MC} \mathbf{C}^{e} \left\{ \Phi^{e} \right\} + \beta^{T} \mathbf{MHI} \mathbf{MHI} \mathbf{C}^{e} \left\{ \Phi^{e} \right\} - \left\{ f^{e} + f^{e}_{q} \right\}^{T} \mathbf{q}^{e} \]

where the undefined terms are :
\[
\mathbf{E}_C = 2 \int_{-1}^{1} \int_{-1}^{1} \mathbf{d}_{\mathbf{B}} \mathbf{J}_\eta \, d\xi \, d\eta \quad , \quad \mathbf{E}_H = 2 \int_{-1}^{1} \int_{-1}^{1} \mathbf{P}^T_{\mathbf{NH}} \mathbf{d}_{\mathbf{B}} \mathbf{J}_\eta \, d\chi \, d\eta \quad , \quad \mathbf{A} = 2 \int_{-1}^{1} \int_{-1}^{1} \zeta \mathbf{B}^T \mathbf{J}_\eta \, d\xi \, d\eta
\]

\[
f^e_0 = -\begin{cases} Q_{\text{TOP}} A_{\text{TOP}} \\ Q_{\text{BOTTOM}} A_{\text{BOTTOM}} \end{cases}
\]

is the elementwise electric force vector

Moreover, \(A_{\text{TOP}}\) and \(A_{\text{BOTTOM}}\) are respectively the areas of the upper and lower element surfaces whereas \(Q_{\text{TOP}}\) and \(Q_{\text{BOTTOM}}\) are respectively the prescribed charge densities, if any, at the upper and lower element surfaces. After condensing \(\mathbf{B}'\)’s with the stationary conditions of \(\Pi^e\) with respect to \(\mathbf{B}'\)’s, the functional can be expressed as:

\[
\Pi^e = \frac{1}{2} \begin{bmatrix} \mathbf{q}^e \end{bmatrix}^T \begin{bmatrix} \mathbf{k}_{\text{nn}}^e & \mathbf{k}_{\text{me}}^e \\ \mathbf{k}_{\text{me}}^e & \mathbf{k}_{\text{ee}}^e \end{bmatrix} \begin{bmatrix} \mathbf{q}^e \end{bmatrix} - \begin{bmatrix} \mathbf{f}^e_0^T + \mathbf{f}_0^a \end{bmatrix} \begin{bmatrix} \mathbf{q}^e \end{bmatrix} 
\]

in which

\[
\mathbf{k}_{\text{nn}}^e = \mathbf{k}_{\text{hom}}^e , \quad \mathbf{k}_{\text{me}}^e = \frac{1}{v} \mathbf{G}^T_{\text{NC}} \mathbf{C}_1 \mathbf{E}_C + \mathbf{G}^T_{\text{NH}} \mathbf{H}^{-1}_{\text{NH}} \mathbf{E}_H , \quad \mathbf{k}_{\text{ee}}^e = \frac{1}{v} \mathbf{E}_C^T \mathbf{C}_1 \mathbf{E}_C + \mathbf{E}_H^T \mathbf{H}^{-1}_{\text{NH}} \mathbf{E}_H - \mathbf{A}
\]

It should be remarked that higher computational efficiency can be yielded by block-diagonalizing the flexibility submatrices \(\mathbf{H}'\)’s in the context of the admissible matrix formulation [17].

### 7. MEMBRANE ELEMENT FOR PIEZOELECTRIC THIN PATCHES

When the thickness of piezoelectric patches is much thinner than that of the host structure (e.g., the typical thickness of PVDF thin films is 20 ~ 100 \(\mu\)m), the piezoelectric patches can be modeled more efficiently by membrane elements whose bending and transverse shear stiffness are negligible and ignored. This section will derive a membrane element by degenerating the solid-shell element presented in Section 6, see Figure 4. The element has four kinetic nodes and one electric node. Each of the kinetic node is equipped with three translational d.o.f.s. The geometric and displacement interpolations are :

\[
\mathbf{X}(\xi, \eta) = \sum_{i=1}^{4} N_i(\xi, \eta) \mathbf{X}_i , \quad \mathbf{U}(\xi, \eta) = \sum_{i=1}^{4} N_i(\xi, \eta) \mathbf{U}_i
\]

From equations (5) and (6), the in-plane membrane strain can be expressed as :

\[
\mathbf{e}_x = \begin{bmatrix} \mathbf{e}_x \\ \mathbf{e}_y \end{bmatrix} = \begin{bmatrix} x_x \xi x_x \eta & x_x x_x x_x & 2x_x \xi \eta \\ y_y \xi y_y \eta & y_y y_y y_y & 2y_y \xi \eta \\ x_x y_y x_y \xi y_y \eta & x_x y \eta x_y \xi & x_x y \eta + x_y \xi \eta \end{bmatrix}^T \begin{bmatrix} \mathbf{X}_\xi^T \mathbf{U}_\xi \\ \mathbf{X}_\eta^T \mathbf{U}_\eta \\ \mathbf{X}_{\xi \eta}^T \mathbf{U}_{\xi \eta} + \mathbf{X}_{\eta \xi}^T \mathbf{U}_{\eta \xi} \end{bmatrix} = \mathbf{B} \mathbf{q}^e
\]
and the electric field component transverse to the element is:

\[
E_{\parallel} = -\frac{\Phi_{\text{TOP}} - \Phi_{\text{BOTTOM}}}{t} = -\frac{1}{t}[1, -1] \begin{bmatrix} \Phi_{\text{TOP}} \\ \Phi_{\text{BOTTOM}} \end{bmatrix} = -\mathbf{E}_{\parallel} \mathbf{\Phi}^e
\]  

(32)

in which \( t \) denotes the thickness. With \( E_x = E_y = \sigma_{||} = \tau_{xx} = \tau_{yy} = 0 \), the constitutive relation in equation (26) can be simplified as:

\[
\begin{bmatrix} \mathbf{e}_e \\ \mathbf{D}_e \end{bmatrix} = \begin{bmatrix} \mathbf{S}_e \\ \mathbf{d}_e \\ \zeta_{||e} \end{bmatrix} \begin{bmatrix} \mathbf{\sigma}_e \\ \mathbf{E}_e \end{bmatrix}
\]

(33)

where \( \mathbf{d}_e \) contains only the first three entries of \( \mathbf{d}_e \). The two-dimensional counterpart of the functional in equation (27) is:

\[
\Pi^e = \frac{1}{2} \int_{-1}^{1+1} \left( \begin{bmatrix} \mathbf{\sigma}_e \\ \mathbf{d}_e \\ \zeta_{||e} \end{bmatrix} \begin{bmatrix} \mathbf{S}_e \end{bmatrix} + \mathbf{\sigma}_e^T \mathbf{e}_e - \mathbf{b}^T \mathbf{U} \right) dv - \int_{s_{c}}^{s_{0}} t^T \mathbf{U} ds + \int_{s_{c}}^{s_{0}} \mathbf{Q} \mathbf{d} ds
\]

\[
= \int_{-1}^{1+1} \left( \begin{bmatrix} \mathbf{\sigma}_e \\ \mathbf{d}_e \end{bmatrix} \begin{bmatrix} \mathbf{S}_e \\ \zeta_{||e} \end{bmatrix} + \mathbf{\sigma}_e^T \mathbf{e}_e - \mathbf{b}^T \mathbf{U} \right) J d \xi d \eta - \int_{s_{c}}^{s_{0}} t^T \mathbf{U} ds + \int_{s_{c}}^{s_{0}} \mathbf{Q} \mathbf{d} ds
\]

(34)

where \( J = t \| \mathbf{X}_{11} \times \mathbf{X}_{\eta} \|. \) The assumed-stress as degenerated from equation (19) is:

\[
\mathbf{\sigma}_e = \mathbf{\beta}_c + \mathbf{\mathbb{P}}_h \mathbf{\beta}_h = \mathbf{\beta}_C + \frac{1}{f} \begin{bmatrix} \xi \bar{\xi}_1 \bar{\eta}_1 \\ \eta \bar{\eta}_1 \bar{\xi}_1 \\ \xi \bar{\eta}_1 \bar{\eta}_1 \\ \eta \bar{\xi}_1 \bar{\eta}_1 \end{bmatrix} \begin{bmatrix} \eta \bar{\xi}_1 \\ \eta \bar{\xi}_1 \\ \eta \bar{\eta}_1 \bar{\xi}_1 \\ \eta \bar{\xi}_1 \bar{\eta}_1 \end{bmatrix} \begin{bmatrix} \mathbf{\beta}_C \end{bmatrix}
\]

(35)

With equations (31), (32) and (35) substituted into equation (34), the latter can be written as:

\[
\Pi^e = -\frac{1}{2} \mathbf{\beta}_C^T \mathbf{S}_c \mathbf{\beta}_C - \frac{1}{2} \mathbf{\beta}_h^T \mathbf{H}_h \mathbf{\beta}_h^T + \mathbf{\beta}_C^T \begin{bmatrix} \mathbf{G}_c & \mathbf{E}_c \end{bmatrix} \begin{bmatrix} \mathbf{q}_c^e \\ \mathbf{\Phi}^e \end{bmatrix} + \mathbf{\beta}_h^T \begin{bmatrix} \mathbf{G}_h & \mathbf{E}_h \end{bmatrix} \begin{bmatrix} \mathbf{q}_h^e \\ \mathbf{\Phi}^e \end{bmatrix}
\]

\[
= -\frac{1}{2} \left( \mathbf{\Phi}^e \right)^T \mathbf{A} \mathbf{\Phi}^e - \begin{bmatrix} \mathbf{f}_c^e \\ \mathbf{f}_h^e \\ \mathbf{f}_q^e \end{bmatrix}^T \begin{bmatrix} \mathbf{q}_c^e \\ \mathbf{q}_h^e \\ \mathbf{q}_q^e \end{bmatrix}
\]

(36)

After condensing \( \mathbf{\beta}'s \) with the stationary conditions of \( \Pi^e \) with respect to \( \mathbf{\beta}'s \), the functional of the present element can also be expressed in the same form as equation (29) except that

\[
\kappa_{mm}^e = \frac{1}{v} \mathbf{G}_c^T \mathbf{S}_c^{-1} \mathbf{G}_c + \mathbf{G}_h^T \mathbf{H}_h^{-1} \mathbf{G}_h, \quad \kappa_{me}^e = \frac{1}{v} \mathbf{G}_c^T \mathbf{S}_c^{-1} \mathbf{E}_c + \mathbf{G}_h^T \mathbf{H}_h^{-1} \mathbf{E}_h, \quad \kappa_{ee}^e = \frac{1}{v} \mathbf{E}_c^T \mathbf{S}_c^{-1} \mathbf{E}_c + \mathbf{E}_h^T \mathbf{H}_h^{-1} \mathbf{E}_h - \mathbf{A}
\]

(37)

in which
Lastly, it should be remarked that the membrane element is rank deficiency and can only be used as an adherent to solid elements.

8. SYSTEM EQUATION AND EIGEN ANALYSIS

After summing all the elementwise functional $\Pi'$ and taking the variation of nodal displacements and electric potential, the system equation can be expressed as:

$$\begin{bmatrix} \mathbf{K}_{mm} & \mathbf{K}_{mc} \\ \mathbf{K}_{mc}^T & \mathbf{K}_{ee} \end{bmatrix} \begin{bmatrix} \mathbf{q} \\ \mathbf{\Phi} \end{bmatrix} = \begin{bmatrix} \mathbf{F}_b + \mathbf{F}_\sigma \\ \mathbf{F}_Q \end{bmatrix} \quad (38)$$

in which $\mathbf{K}$’s are assembled from the element matrices $\mathbf{k}$’s; $\mathbf{q}$ and $\mathbf{\Phi}$ are the system vectors of nodal displacements and electric potentials, respectively; $\mathbf{F}_b$, $\mathbf{F}_\sigma$ and $\mathbf{F}_Q$ are the assembled counterparts of $\mathbf{f}_b^*$, $\mathbf{f}_\sigma^*$ and $\mathbf{f}_Q^*$, respectively. For dynamic analysis, the inertia and damping forces can be accounted for in terms of the body force, i.e.

$$\mathbf{F}_b = -\mathbf{M}\ddot{\mathbf{q}} - \mathbf{C}\dot{\mathbf{q}} = -\mathbf{M}\ddot{\mathbf{q}} - (\alpha \mathbf{M} + \beta \mathbf{K}_{mm})\dot{\mathbf{q}} \quad (39)$$

in which $\alpha$ and $\beta$ are the Rayleigh’s damping coefficients, $\mathbf{M}$ is the mass matrix assembled from $\int \rho N^T N dv$ and $\rho$ is the mass density. Thus, the system equation can be expanded as:

$$\begin{bmatrix} \mathbf{M} & 0 \\ 0 & 0 \end{bmatrix} \begin{bmatrix} \ddot{\mathbf{q}} \\ \dot{\mathbf{\Phi}} \end{bmatrix} + \begin{bmatrix} \mathbf{C} & 0 \\ 0 & 0 \end{bmatrix} \begin{bmatrix} \dot{\mathbf{q}} \\ \dot{\mathbf{\Phi}} \end{bmatrix} + \begin{bmatrix} \mathbf{K}_{mm} & \mathbf{K}_{mc} \\ \mathbf{K}_{mc}^T & \mathbf{K}_{ee} \end{bmatrix} \begin{bmatrix} \mathbf{q} \\ \mathbf{\Phi} \end{bmatrix} = \begin{bmatrix} \mathbf{F}_b \\ \mathbf{F}_\sigma \end{bmatrix} \quad (40)$$

Natural frequencies and their mode shapes can be obtained by setting right hand vector to zero and condensing $\mathbf{\Phi}$ with $\mathbf{\Phi} = \mathbf{K}_{\sigma}^{-1} \mathbf{K}_{mc}^T \mathbf{q}$.

9. ACTIVE CONTROL OF SMART STRUCTURES

Figure 1 shows a typical configuration of smart structure with piezoelectric sensors and actuators. The sensors sense the strains of the host structure and produce electrical potentials. The signals are fed into controllers which implement certain control algorithms. Outputs of the controllers are used
to strain the actuators which in term strain the host structure. By partitioning the system vector of electric potential $\Phi$ into that of the actuators $\Phi^d$ and of the sensors $\Phi^s$, equation (40) can be split into:

$$\begin{align*}
M\ddot{q} + C\dot{q} + [K_{nm}\dot{q} + K_{me}\Phi^d + K_{me}\Phi^s = F_\sigma ,
\{\Phi^d, \Phi^s\} = \left[\begin{array}{cc}
(K_{ee})^{-1} & 0 \\
0 & (K_{ee})^{-1}
\end{array}\right]
\left[\begin{array}{c}
F^d \\
F^s
\end{array}\right] - \left[\begin{array}{c}
(K_{me})^T \\
(K_{me})^T
\end{array}\right]q
\end{align*}$$

(41)

where

$$\begin{align*}
\{\Phi^d, \Phi^s\} = \Phi, \left[\begin{array}{cc}
(K_{ee})^{-1} & 0 \\
0 & (K_{ee})^{-1}
\end{array}\right] = K_{ee}^{-1}, [K_{me}, K_{me}] = K_{me}, \left[\begin{array}{c}
F^d \\
F^s
\end{array}\right] = F_Q .
\end{align*}$$

In particular, $K_{ee}$ is block diagonal because the host structure is non-piezoelectric, i.e. $\Phi^d$ and $\Phi^s$ do not couple. As there is no electric loading applied to the sensors, $F_Q^s$ vanishes. Consequently, equation (41) gives:

$$\Phi^s = -(K_{ee})^{-1}(K_{me})^T q ,$$

(42)

which gives sensor outputs and can be processed to provide input signals to the actuators for active vibration control. Substitution of equation (42) into equation (41) results in:

$$\begin{align*}
M\ddot{q} + C\dot{q} + [K_{nm} - K_{me}(K_{ee})^{-1}(K_{me})^T]q = F_\sigma - K_{me}\Phi^d .
\end{align*}$$

(43)

With the control algorithm known and by virtue of equation (43), $\Phi^d$ can be expressed in terms of $q$ and thus all the electric d.o.f.s in equation (43) can be condensed.

For active damping, negative velocity feedback can be adopted as the control algorithm with which $\Phi^s$ and $\Phi^d$ can be related by a control gain matrix $T_q$, namely,

$$\Phi^d = -T_q \Phi^s .$$

(44)

With equation (42), equations (43) and (44) become

$$\begin{align*}
\Phi^d = T_q (K_{ee})^{-1}(K_{me})^T \dot{q} ,
M\ddot{q} + (C + \overline{C})\dot{q} + Kq = F_\sigma
\end{align*}$$

(45)

where

$$\begin{align*}
\overline{C} = K_{me} T_q (K_{ee})^{-1}(K_{me})^T ,
K = K_{nm} - K_{me}(K_{ee})^{-1}(K_{me})^T
\end{align*}$$

Matrices $C$ and $\overline{C}$ will be termed as passive and active damping matrices which are due to material dissipation and active damping effect of the smart structure, respectively.
By means of modal analysis, the global displacement $\mathbf{q}$ can be expressed in terms of the vector of modal generalized displacements $\mathbf{\Theta}$ as:

$$
\mathbf{q} = \mathbf{Y} \mathbf{\Theta} \quad (46)
$$

in which $\mathbf{Y} = [\mathbf{\Psi}_1, \mathbf{\Psi}_2, \ldots, \mathbf{\Psi}_i, \ldots]$ is the square matrix that contains all the normalized eigenvectors $\mathbf{\Psi}_j$’s of the undamped system as its column vectors, i.e.

$$(\mathbf{K} - \omega_i^2 \mathbf{M})\mathbf{\Psi}_j = \mathbf{0} \quad (47)$$

where $\omega_i$ is the eigenvalue pertinent to $\mathbf{\Psi}_j$. Substituting equation (46) into equation (45) and multiplying the latter with the transpose of $\mathbf{\Psi}^T$, we have

$$
\mathbf{Y}^T \mathbf{M} \mathbf{Y} \dot{\mathbf{\Theta}} + \mathbf{Y}^T (\mathbf{C} + \mathbf{\bar{C}}) \mathbf{\Theta} + \mathbf{Y}^T \mathbf{K} \mathbf{Y} \mathbf{\Theta} = \mathbf{Y}^T \mathbf{F}_o \quad (48)
$$

By using the orthonormal property of the modal matrix, the above equation can be simplified as:

$$
\ddot{\mathbf{\Theta}} + (\text{diag.}\{2\mu_i, \omega_i, \ldots, 2\mu_i, \omega_i, \ldots\} + \mathbf{Y}^T \mathbf{\bar{C}} \mathbf{Y}) \dot{\mathbf{\Theta}} + \text{diag.}\{\omega_i^2, \omega_i^2, \ldots\} \mathbf{\Theta} = \mathbf{Y}^T \mathbf{F}_o \quad (49)
$$

in which $\mu_i = (\alpha + \beta \omega_i^2)/(2\omega_i)$ is the *passive damping ratio* arising from the Rayleigh’s damping. In case of $\mathbf{Y}^T \mathbf{\bar{C}} \mathbf{Y}$ being diagonal, the system response can be solved by the classical mode superposition method. In particular, if only the first-mode is considered, the governing equation can be reduced from equation (49) as:

$$
\ddot{\theta}_i + 2(\mu_i + \bar{\mu}_i)\omega_i \dot{\theta}_i + \omega_i^2 \theta_i = 0, \quad (50)
$$

where $\bar{\mu}_i$ is the *active damping ratio* induced by the control algorithm and is equal to the $(1,1)$-entry of $\mathbf{Y}^T \mathbf{\bar{C}} \mathbf{Y}$ divided by $2\omega_i$. 
10. NUMERICAL EXAMPLES

In this section, a number of problems related to smart structure modelling are studied by the elements derived in Sections 4, 5, 6 and 7. The adhesive in between the host structures and the piezoelectric patches will be assumed to be thin enough for negligence. Thus, the concept of using viscoelastic constraint layers for passive damping will not be studied.

10.1. Bimorph Pointer

This bimorph pointer is portrayed in Figure 5. It consists of two identical PVDF layers ($E = 2$ GPa, $\nu = 0.29$, $e_{31} = e_{32} = 0.046$ C/m$^2$, $e_{33} = 0.1062$ nF/m) with vertical but opposite polarities and, hence, will bend when an electric field is applied vertically. The bimorph is modeled by $2 \times 5$ elements. With a unit voltage applied across the thickness, the deflection of bimorph beam is computed by the present piezoelectric solid-shell element and compared with the theoretical and other finite element predictions as listed in Table 1. It can be seen that the present solid-shell element model matches theoretical results up to four significant figures.

The tip deflection of the bimorph is then prescribed to 1 cm and the open circuit voltage output across the thickness is computed. Figure 6 shows the predicted voltage when 1, 5 and 10 electrode (metallization) pairs are employed. The related meshes contain $2 \times 5$, $2 \times 5$ and $2 \times 10$ elements. The predictions show excellent agreement with the analytical solution [20] in which the equipotential effect induced by the metallization is ignored and thus the electric potential is a continuous function of $x$.

<table>
<thead>
<tr>
<th>Distance $x$ (mm)</th>
<th>20</th>
<th>40</th>
<th>60</th>
<th>80</th>
<th>100</th>
</tr>
</thead>
<tbody>
<tr>
<td>Tseng* [10]</td>
<td>0.150</td>
<td>0.569</td>
<td>1.371</td>
<td>2.351</td>
<td>3.598</td>
</tr>
<tr>
<td>Tzou* [20]</td>
<td>0.124</td>
<td>0.508</td>
<td>1.16</td>
<td>2.10</td>
<td>3.30</td>
</tr>
<tr>
<td>Tzou &amp; Ye* [7]</td>
<td>0.132</td>
<td>0.528</td>
<td>1.19</td>
<td>2.11</td>
<td>3.30</td>
</tr>
<tr>
<td>Wang, Chen &amp; Han [9]</td>
<td>0.139</td>
<td>0.547</td>
<td>1.135</td>
<td>2.198</td>
<td>3.416</td>
</tr>
<tr>
<td>Detwiler, Shen &amp; Venkayya [6]</td>
<td>0.14</td>
<td>0.55</td>
<td>1.24</td>
<td>2.21</td>
<td>3.45</td>
</tr>
<tr>
<td>Analytical [20]</td>
<td>0.138</td>
<td>0.552</td>
<td>1.242</td>
<td>2.208</td>
<td>3.450</td>
</tr>
<tr>
<td>Present*</td>
<td>0.138</td>
<td>0.552</td>
<td>1.242</td>
<td>2.208</td>
<td>3.450</td>
</tr>
</tbody>
</table>

* the elements derived are solid or solid shell elements

The effect of mesh distortion on the element accuracy is then studied. The bimorph is modelled by
2×4 elements as shown in Figure 7. With a unit voltage applied across the thickness, the free end deflection is computed by the present element and the following piezoelectric solid elements in ABAQUS [21]:

- C3D8E – the 8-node piezoelectric brick element
- C3D20ER – the 20-node reduced integrated piezoelectric brick element

Using the beam theory in which a plane stress condition is assumed in the Y-direction, the analytical end deflection is 0.345 µm. To assess the element accuracy by the beam solution, the Poisson’s ratio is set to zero for mimicking the required plane stress condition. The predicted end deflections for different element distortions “e” are plotted in Figure 8. Without resorting to any advanced finite element technique, C3D8E is very poor in accuracy. Despite of the higher order nature of C3D20ER, its accuracy is marginally lower than the present element whose prediction is graphically indistinguishable from the beam solution.

10.2. Aluminum Square Plate with a Circular Piezoelectric Wafer

Figure 9 shows a 305×305×0.8 mm fully clamped aluminum square plate (ρ = 2800 kg/m³, E = 68 GPa, ν = 0.32) with a φ20 mm piezoelectric wafer bonded to its center. The wafer is 1 mm thick and made of PZT-5H (ρ = 7500 kg/m³, E₁ = E₂ = 62.5 GPa, E₃=57.16 GPa, G₄₄ = G₅₅ = 23 GPa, G₆₆ = 23.3 GPa, ν₁₂ = 0.3345, ν₁₃ = ν₂₃ = 0.442, ε₁₁ = ε₂₂ = -6.5 C/m², ε₃₃ = 23.3 C/m², ε₃₃ = 13 nF/m). A 1 Pa uniform pressure is applied to the lower surface of the plate. The mesh layout is essentially the same as the one used by Kim, Varadan & Varadan [8] who employed 192 nine-node flat shell, 8 thirteen-node solid-to-plate transition, 4 twenty-node solid and 4 twenty-node piezoelectric solid elements [8]. In the present analysis, 200 solid-shell and 12 piezoelectric solid-shell elements are employed. The static central deflections with and without the wafer are listed in Table 2. Given the high accuracy of the result in the absence of the wafer and the relative dimension of the plate and the wafer (area ratio ≈ 300 : 1), the predicted deflection of Kim et al appears to be too small. It is noteworthy that the ratio of the active d.o.f.s in Kim et al’s mesh and the present one is ≈ 3 : 1, not to mention the modelling burden of co-using four different types of elements.

Figure 10 shows the peak voltage output of the wafer when the plate is subjected to sinusoidal pressure loading. The first two peaks predicted by the present elements are 74.20Hz and 284.16 Hz whereas the predictions of Kim, Varadan & Varadan [8] are 78.5 Hz and 279.5 Hz. The differences in the first and second peaks are ≈ 5% and ≈ 4%. In the absence of the piezoelectric wafer, series
solutions [23] and the predictions of the present element for the first two symmetric eigen modes are 74.06 / 270.9 and 74.81 / 290.0 Hz, respectively. The difference in the first eigen frequency is ≈ 1%. It should be remarked that the voltage does not peak at the unsymmetric eigenmode in which the centre of plate is stationary.

| Table 2. Static central deflection for the clamped square aluminum plate, see Figure 9 |
|---------------------------------|---------------------|---------------------|
|                                 | without wafer (µm)  | with wafer (µm)     |
| Kim, Varadan & Varadan [8]      | not available       | 2.465               |
| present                        | 3.381               | 3.253               |
| series solution [22]            | 3.380               | not available       |

10.3. Cantilever Composite Plate With Distributed Actuators

Figure 11 shows a composite cantilever plate with twenty-two square and eight non-square surface bonded G-1195 piezoelectric ceramic patches (ρ = 7600 kg/m³, E = 63.0 GPa, G = 24.2 GPa, ν = 0.3, d₁₁ = d₁₂ = 254 pm/V, d₁₃ = 374 pm/V, d₂₄ = 584 pm/V, ζ₁₁ = ζ₁₂ = 15.3 nF/m, ζ₁₃ = ζ₂₃ = 15.0 nF/m). Stacking of the composite plate is [0°/±45°]₅ and the plate is made of T300/976 graphite/epoxy unidirectional laminae (ρ = 1600 kg/m³, Eᵢ = 150 GPa, Eᵣ = 9 GPa, Gᵤ = 7.1 GPa, Gᵥ = 2.5 GPa, νᵢ = νᵥ = 0.3). Following the mesh of Ha, Keilers & Chang [1], the host plate is modeled by 10×16 elements. A voltage supply of 98.5 V is applied to the piezoelectric patches such that the ones above and below the composite plate are subjected to equal but opposite electric field of magnitude 389 V/mm. The following non-dimensional deflection parameters are computed by the present element models and shown in Figures 12 to 14:

\[
W_L = \frac{W}{y=7.6cm}C, \quad W_T = \frac{W}{y=7.6cm} - \left(\frac{W}{y=15.2cm} + \frac{W}{y=0cm}\right)/2 \quad \text{and} \quad W_R = \frac{W}{y=15.2cm} - \frac{W}{y=0cm} \frac{C}{C}
\]

which correspond to longitudinal bending, transverse bending and lateral twisting deflections. In the above equations, C = 15.2 cm is the width of the plate. For comparative purpose, the experimental results of Crawly & Lazarus [24] and the finite element predictions of Ha, Keilers & Chang [1] are also included in the figures. The element models developed by Ha, Keilers & Chang are eight-node solid elements with nine incompatible displacement modes. These incompatible elements suffer from shear locking when the elements are not in the form of rectangular prisms [25]. Despite of the regular geometry of the elements in this example, Wₗ predicted by the incompatible models are apparently smaller than that obtained by the present models and the experimental measurement.
10.4. Steel Ring with Segmented Sensors and Actuators

Figure 15 shows a 6.35 mm thick semi-circular steel ring ($\rho = 7750$ kg/m$^3$, $E = 68.95$ GPa, $\nu = 0.3$) sandwiched by two PZT layers ($\rho = 7600$ kg/m$^3$, $E = 63$ GPa, $\nu = 0.3$, $d_{31} = 179$ pm/V, $\varepsilon_{33} = 16.50$ nF/m). Thickness of the PZT layers are taken to be either 254 $\mu$m or 50.8 $\mu$m.

In the absence of the PZT layers, the lowest eigen frequencies of the steel ring are computed and listed in Table 3. For comparative purpose, predictions of the following ABAQUS [21] curved shells:

- S4 – the 4-node general-purpose (thin and thick) shell element
- S4R5 – a stabilized reduced-integrated 4-node thin shell element with 5 d.o.f. per node
- S9R5 – a stabilized reduced-integrated 9-node thin shell element with 5 d.o.f. per node

as well as Tzou & Ye’s twelve-node triangular prismatic solid element [7] are also included. The predictions of S4 and the present solid-shell element are insensitive to the mesh density. This implies that the mesh densities have been adequate for the two element models to give reasonably converged results. With 1×10 elements, predicted frequencies of S4R5 are very low. The observation is probably due to the hourglass modes which are stabilized by small stiffness parameters. Nevertheless, close results are yielded by S4, S4R5 and the present element using 2×20 elements as well as S9R5 using 1×10 elements. The eigen frequencies computed by Tzou & Ye’s element indicates that the element is too stiff.

In the subsequent computations, the ring is modelled by 1×10 elements. A tip circumferential load of 100 N/m is applied along the negative Z-direction. The voltage outputs of the ten piezoelectric elements modelling the inner PZT layer are plotted in Figure 16. The strain is largest at the clamped end and so is the voltage output. The voltage predictions by the solid-shell and membrane piezoelectric elements are graphically indistinguishable except at the vicinity of the clamped end for both thick and thin PZT layers.

The ring shell is then sandwiched by 1 pair (10% of the ring counting from the clamped end is covered) to 10 pairs (100% is covered) of PZT patches. The inner and outer patches serve respectively as sensors and actuators which are linked by negative velocity feedback controller(s) of unit gain. Figures 17 and 18 show the damping ratio for the first eigenmode with different number of S/A (sensor/actuator) pairs constituted by thick (254 $\mu$m) and thin (50.8 $\mu$m) PZT patches, respectively. With only one controller (all sensing patches are electrically connected and so are the actuating patches), the damping ratio increases rapidly from zero S/A pair to four S/A pairs, reaches its peak and starts to drop at five S/A pairs. With multiple controllers where each S/A pair employs
a separate controller, the damping ratio increases monotonically with the number of S/A pairs. It is noteworthy that the control effectiveness of using one controller is better than that of using multi-controllers. Comparing Figures 17 and 18, the membrane approximation of the PZT patches is more realistic for the thinner patches.

### Table 3. The eigen frequencies (in Hz) for the steel ring (without the PZT layers) in Figure 11

<table>
<thead>
<tr>
<th></th>
<th>mesh</th>
<th>mode 1</th>
<th>mode 2</th>
<th>mode 3</th>
<th>mode 4</th>
<th>mode 5</th>
</tr>
</thead>
<tbody>
<tr>
<td>S4 shell</td>
<td>1×10</td>
<td>3.6552</td>
<td>6.0444</td>
<td>12.301</td>
<td>34.944</td>
<td>44.092</td>
</tr>
<tr>
<td></td>
<td>2×20*</td>
<td>3.6920</td>
<td>5.9455</td>
<td>11.965</td>
<td>34.043</td>
<td>41.446</td>
</tr>
<tr>
<td>S4R5 shell</td>
<td>1×10</td>
<td>3.2930</td>
<td>3.7298</td>
<td>9.2736</td>
<td>12.102</td>
<td>32.565</td>
</tr>
<tr>
<td></td>
<td>2×20*</td>
<td>3.7439</td>
<td>5.9033</td>
<td>11.911</td>
<td>33.342</td>
<td>41.238</td>
</tr>
<tr>
<td>S9R5 shell</td>
<td>1×10†</td>
<td>3.7475</td>
<td>5.8971</td>
<td>11.856</td>
<td>33.634</td>
<td>40.626</td>
</tr>
<tr>
<td>present</td>
<td>1×10</td>
<td>3.6822</td>
<td>5.8278</td>
<td>11.838</td>
<td>33.641</td>
<td>42.295</td>
</tr>
<tr>
<td></td>
<td>2×20‡</td>
<td>3.6810</td>
<td>5.8041</td>
<td>11.691</td>
<td>33.231</td>
<td>40.450</td>
</tr>
<tr>
<td>Tzou &amp; Ye [7]</td>
<td>2×10§</td>
<td>8.17</td>
<td>25.66</td>
<td>86.93</td>
<td>194.14</td>
<td>346.08</td>
</tr>
</tbody>
</table>

* denotes the same number of nodes and d.o.f.s; † denotes the same number of nodes and d.o.f.s

#### 10.5. Square Plate with Segmented Sensors and Actuators

Figure 19 shows a simply supported 1.6 mm thick plexiglas square plate ($\rho = 1190$ kg/m$^3$, $E = 3.1$ GPa, $\nu = 0.35$) with eight 40 $\mu$m thick surface bonded PVDF films ($\rho = 1800$ kg/m$^3$, $E = 2.0$ GPa, $\nu = 0.2$, $d_{31} = d_{32} = 10$ pm/V, $\varepsilon_{33} = 0.1062$ nF/m). The films bonded to the top and bottom faces are used as actuators and sensors, respectively [5]. The plexiglas plate is modelled by 17×17 elements whereas each PVDF film is modelled by 7×7 elements. The gap between the PVDF film is not specified in reference [5] and is here taken rather arbitrary to be 1/200 of plexiglas length. In the absence of the PVDF films, the eigen frequencies of the plate is predicted and compared to that obtained by Tzou, Tseng & Bahrami’s solid element. For comparative purpose, the frequencies are also computed with the PVDF films included and with a 17×17 uniform mesh. It can be seen that the element of Tzou, Tseng & Bahrami is accurate only for the first mode whereas the present solid-shell element is still reasonably accuracy for the third mode. It is noted that Tzou, Tseng & Bahrami’s solid elements [7] and Ha, Keilers & Chang’s solid elements [1] are highly similar, if not identical, in the sense that they all contains nine incompatible displacement modes and, thus, exhibit shear locking when the elements are not in the form of rectangular prisms [25].

With the passive damping coefficient of the smart plate taken to be 0.01, the initial deflection of the composite plate structure is prescribed according to first eigenmode at 1 mm amplitude. The signals from the four sensors are input into four negative velocity feedback controllers which drive the four actuators immediately above the respective sensors. Figure 20 shows the ten percent settling time versus the controller gain. As only the first mode is focused, the results predicted by present solid-shell elements and Tzou, Tseng & Bahrami’s incompatible are in good agreement.
The PDVF films are also modeled by the piezoelectric membrane elements. The prediction is graphically indistinguishable from that of the piezoelectric solid-shell elements by virtue of the fact that the plexiglass is 400 times thicker than the PDVF.

TABLE 3. Eigen frequencies (in Hz) of the simplify supported plexiglas square plate in Figure 15

<table>
<thead>
<tr>
<th>Modes</th>
<th>m = 1, n = 1</th>
<th>m = 1, n = 2</th>
<th>m = 2, n = 2</th>
</tr>
</thead>
<tbody>
<tr>
<td>Tzou, Tseng &amp; Bahrami w/o PVDF [7]</td>
<td>15.9</td>
<td>41.7</td>
<td>70.6</td>
</tr>
<tr>
<td>non-uniform mesh w/o PVDF</td>
<td>15.688</td>
<td>39.782</td>
<td>63.681</td>
</tr>
<tr>
<td>uniform mesh w/o PVDF</td>
<td>15.672</td>
<td>39.523</td>
<td>63.263</td>
</tr>
<tr>
<td>non-uniform mesh with PVDF</td>
<td>15.803</td>
<td>40.082</td>
<td>64.132</td>
</tr>
<tr>
<td>series solution [23]</td>
<td>15.524</td>
<td>39.060</td>
<td>62.496</td>
</tr>
</tbody>
</table>

* m and n is the numbers of peaks in the eigenmodes along the X- and Y-directions

11. CLOSURE

In this paper, a number of finite element models are developed for modelling smart structures with surface bonded piezoelectric patches. New solid-shell elements are formulated for modelling homogeneous and laminated host structures. Assumed natural strain method is employed to resolve the shear and trapezoidal lockings observed in conventional solid elements whereas hybrid stress method is employed to improve the inplane element response. Piezoelectric solid-shell and membrane elements are developed by including the electromechanical coupling effect. Unlike the conventional piezoelectric elements, the poling direction of the piezoelectric material is assumed to be parallel to the transverse direction of the elements as it always happens in practice. Moreover, the notion of electric nodes is introduced that can conveniently take into account of the equipotential effect induced by the metallization coated on the piezoelectric material. Several examples are examined to illustrate the accuracy and efficacy of the derived models. In particular, the piezoelectric membrane element offers a more economic and convenient choice for modelling thin piezoelectric patches than its solid-shell counterpart.

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APPENDIX

By changing objects of the equation in Eqn.(10), the constitutive relation for a generic lamina can
be expressed as:

\[
\begin{bmatrix}
\sigma_x \\
\epsilon_{ij}
\end{bmatrix} =
\begin{bmatrix}
A & B \\
-B^T & D
\end{bmatrix}
\begin{bmatrix}
\epsilon_x \\
\sigma_{ij}
\end{bmatrix} =
\begin{bmatrix}
S^{-1} & -S^{-1}S_x \\
S_x^T S^{-1} & S_x^T S^{-1} S_x
\end{bmatrix}
\begin{bmatrix}
\epsilon_x \\
\sigma_{ij}
\end{bmatrix}
\]

where

\[
\begin{bmatrix}
C_x & C_z \\
C_z^T & C_{zz}
\end{bmatrix} =
\begin{bmatrix}
S & S \\
S_x^T & S_x
\end{bmatrix}^{-1} =
\begin{bmatrix}
S_x^{-1} + S_x^{-1} S_x S_x^{-1} S_x^{-1} / (S_x - S_x S_x^{-1} S_x) & -S_x^{-1} S_x / (S_x - S_x S_x^{-1} S_x) \\
-S_x^{-1} S_x^{-1} / (S_x - S_x S_x^{-1} S_x) & 1 / (S_x - S_x S_x^{-1} S_x)
\end{bmatrix}
\]

In order to inhibit thickness locking (also known as Poisson’s locking) and recognize the thickness average nature of \(\epsilon_{ij}\) in the element, the modified generalized stiffness matrix for replacing \(\mathbf{C}_G\) is derived as [26]:

\[
\tilde{\mathbf{C}}_G =
\begin{bmatrix}
A_0 + B_0 B_0^T / D_0 & B_0 / D_0 & A_1 + B_0 B_1^T / D_0 \\
B_0^T / D_0 & 1 / D_0 & B_1^T / D_0 \\
A_1 + B_1 B_0^T / D_0 & B_1 / D_0 & A_2 + B_1 B_1^T / D_0
\end{bmatrix}
\]

in which

\[
[A_0, A_1, A_2, B_0, B_1, D_0] = \frac{1}{2} \int_{-1}^{1} [A, \zeta A, \zeta^2 A, B, \zeta B, D] d\zeta
\]

For homogeneous materials, the material constitutive coefficients are independent of \(\zeta\). Thus,

\[
A_0 = A, A_1 = 0_{3x3}, A_2 = A / 3, B_1 = 0_{3x1}, B_0 = B, D_0 = D \quad \text{and} \quad \tilde{\mathbf{C}}_G =
\begin{bmatrix}
C_x & C_z & 0_{3x3} \\
C_z^T & C_{zz} & 0_{3x3} \\
0_{3x3} & 0_{3x1} & C_x / 3
\end{bmatrix}
\]

whereas

\[
\mathbf{C}_G =
\begin{bmatrix}
C_x & C_z & 0_{3x3} \\
C_z^T & C_{zz} & 0_{3x3} \\
0_{3x3} & 0_{3x1} & C_x / 3
\end{bmatrix}
\]
REFERENCES


Figure 1. Configuration of a smart structure with sensor and actuator.

Figure 2. A thin eight-node thin hexahedral solid element.

Figure 3. Solid elements modelling the same piezoelectric patch share the same electric node. Connectivities of the elements are [a, c, j, h, b, d, k, i, p] and [c, f, m, j, d, g, n, k, p].

Figure 4. Membrane elements modelling the same piezoelectric film share the same electric node. Connectivities for the elements are [a, d, f, d, p] and [b, c, g, f, p].
Figure 5. A bimorph cantilever modeled by $2 \times 5$ elements.

Figure 6. Convergence of sensor voltage for a prescribed tip deflection, see Figure 5.

Figure 7. The bimorph cantilever modeled by $2 \times 4$ distorted elements.
Figure 8. End deflections versus distortion for the bimorph cantilever problem, see Figure 7.

Figure 9. (a) A clamped square aluminum plate with a circular PZT patch. (b) The employed mesh.

Figure 10. Sensor response of aluminum square plate under pressure loading, see Figure 9.
Figure 11. A cantilever composite plate with thirty surface-bonded piezoelectric actuators.

Figure 12. Non-dimensional longitudinal bending deflection of cantilever plate in Figure 11.

Figure 13. Non-dimensional transverse bending deflection of the cantilever plate in Figure 11.
Figure 14. Non-dimensional lateral twisting deflection of the cantilever plate in Figure 11.

Figure 15. Semi-circular Steel ring with surface bonded PZT patches

Figure 16. Voltage output of inner PZT layer bonded to the semi-circular ring in Figure 15.
Figure 17. Damping ratio of the ring in Figure 15 versus the number of thick piezoelectric pairs.

Figure 18. Damping ratio of the ring in Figure 15 versus the number of thin piezoelectric pairs.

Figure 19. A plexiglas plate with segmented PVDF piezoelectric sensors and actuators, \( L = 400 \text{ mm}, c = 2 \text{ mm}, h = 1.6 \text{ mm}, t = 0.04 \text{ mm}. \)
Figure 20. Ten percent setting time for the plexglas plate in Figure 16 versus feedback gains